

# SANYO Semiconductors DATA SHEET

An ON Semiconductor Company

# EMH2407 — General-Purpose Switching Device Applications

#### **Features**

- · Low ON-resistance
- · Best suited for LiB charging and discharging switch
- · Common-drain type
- · 2.5V drive
- · Protection diode in

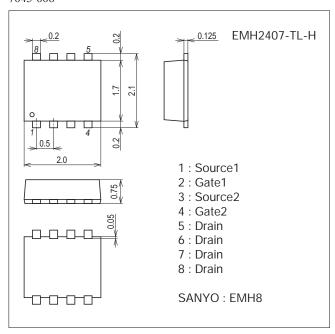
#### **Specifications**

#### Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V <sub>DSS</sub>		20	V
Gate-to-Source Voltage	VGSS		±12	V
Drain Current (DC)	ID		6	А
Drain Current (Pulse)	IDP	PW≤10μs, duty cycle≤1%	40	А
Allowable Power Dissipation	PD	When mounted on ceramic substrate (900mm <sup>2</sup> x0.8mm) 1unit	1.3	W
Total Dissipation	PT	When mounted on ceramic substrate (900mm <sup>2</sup> x0.8mm)	1.4	W
Channel Temperature	Tch		150	°C
Storage Temperature	Tstg		-55 to +150	°C

#### **Package Dimensions**

unit : mm (typ) 7045-006



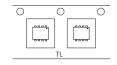
#### **Product & Package Information**

• Package : EMH8

• JEITA, JEDEC : -

• Minimum Packing Quantity : 3,000 pcs./reel

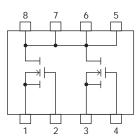
#### Packing Type : TL



#### Marking



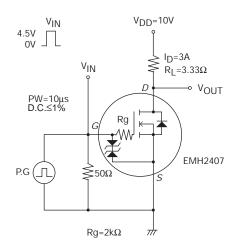
#### **Electrical Connection**



#### Electrical Characteristics at Ta=25°C

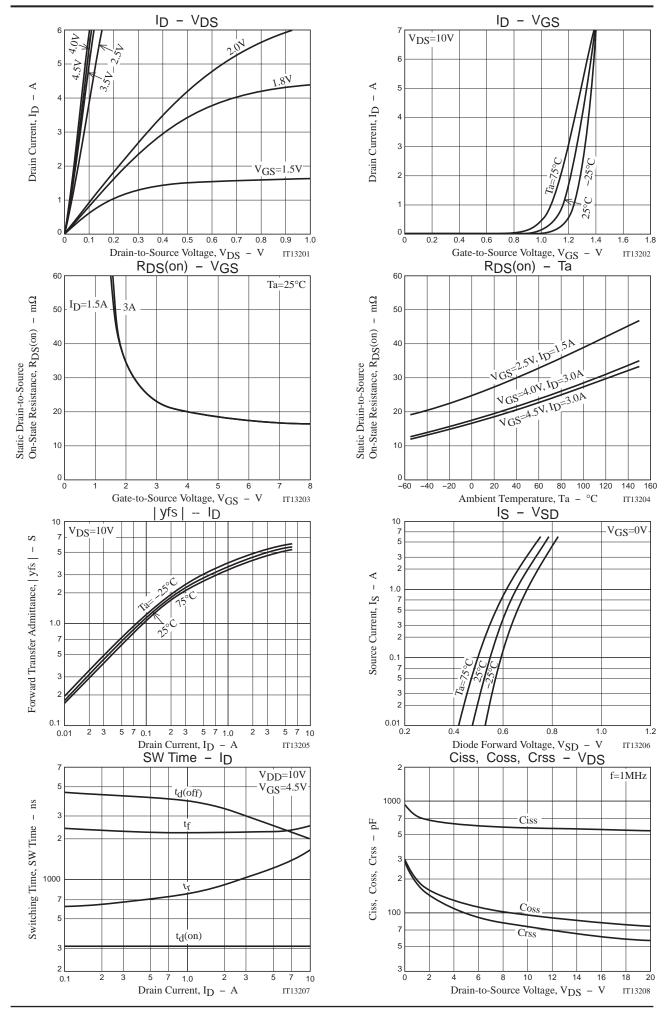
Parameter	Cumbal	Conditions	Ratings			Unit	
Parameter	Symbol	Conditions	min	typ	max	Uniii	
Drain-to-Source Breakdown Voltage	V(BR)DSS	ID=1mA, VGS=0V	20			V	
Zero-Gate Voltage Drain Current	IDSS	V <sub>DS</sub> =20V, V <sub>GS</sub> =0V			1	μΑ	
Gate-to-Source Leakage Current	IGSS	V <sub>GS</sub> =±8V, V <sub>DS</sub> =0V			±10	μΑ	
Cutoff Voltage	V <sub>GS</sub> (off)	V <sub>DS</sub> =10V, I <sub>D</sub> =1mA	0.5		1.3	V	
Forward Transfer Admittance	yfs	V <sub>DS</sub> =10V, I <sub>D</sub> =3A	3	5		S	
Static Drain-to-Source On-State Resistance	R <sub>DS</sub> (on)1	I <sub>D</sub> =3A, V <sub>G</sub> S=4.5V	13	19	25	mΩ	
	R <sub>DS</sub> (on)2	I <sub>D</sub> =3A, V <sub>GS</sub> =4V	14	20	26	mΩ	
	R <sub>DS</sub> (on)3	I <sub>D</sub> =1.5A, V <sub>GS</sub> =2.5V	16	28	39	mΩ	
Input Capacitance	Ciss			580		pF	
Output Capacitance	Coss	V <sub>DS</sub> =10V, f=1MHz		95		pF	
Reverse Transfer Capacitance	Crss			75		pF	
Turn-ON Delay Time	t <sub>d</sub> (on)			310		ns	
Rise Time	t <sub>r</sub>	Considered Total Circuit		1020		ns	
Turn-OFF Delay Time	t <sub>d</sub> (off)	See specified Test Circuit.		3000		ns	
Fall Time	tf			2250		ns	
Total Gate Charge	Qg			6.3		nC	
Gate-to-Source Charge	Qgs	V <sub>DS</sub> =10V, V <sub>GS</sub> =4.5V, I <sub>D</sub> =6A		0.83		nC	
Gate-to-Drain "Miller" Charge	Qgd	]		1.9		nC	
Diode Forward Voltage	V <sub>SD</sub>	IS=6A, VGS=0V		0.78	1.2	V	

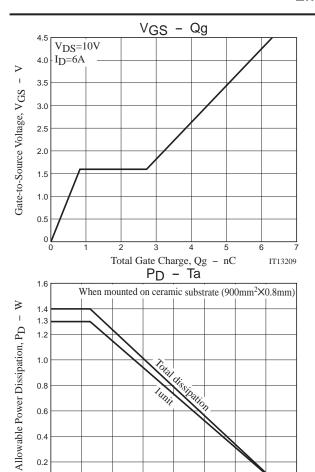
#### Switching Time Test Circuit



#### **Ordering Information**

Device	Device Package		memo	
EMH2407-TL-H	EMH8	3,000pcs./reel	Pb Free and Halogen Free	





80

Ambient Temperature, Ta - °C

100

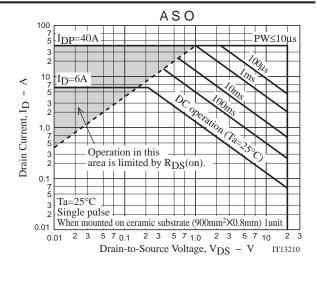
160

IT13211

0

0

20

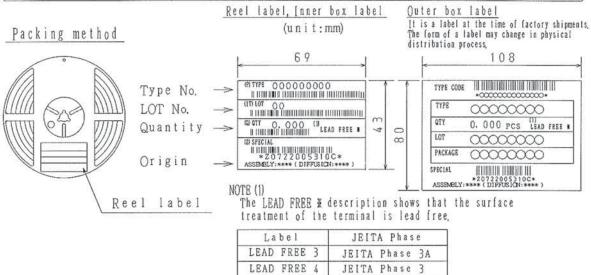


#### **Embossed Taping Specification**

#### EMH2407-TL-H

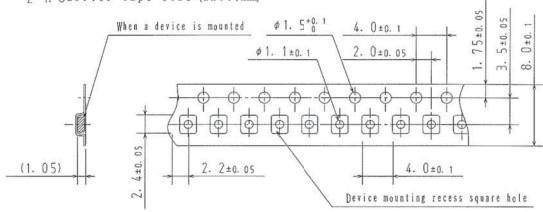
#### 1. Packing Format

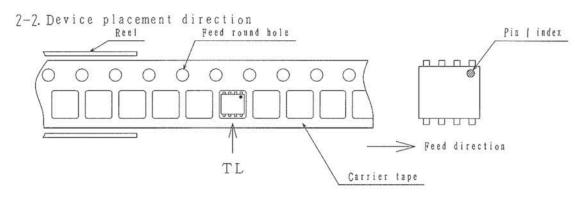
Package Name   Carrier Tape   Type	Maximum Number of devices contained (pcs)			Packing format		
	Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)	
EMH8	MCP4	3, 000	15, 000	90, 000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) $440 \times 195 \times 210$



#### 2. Taping configuration

7-1. Carrier tape size (unit:mm)

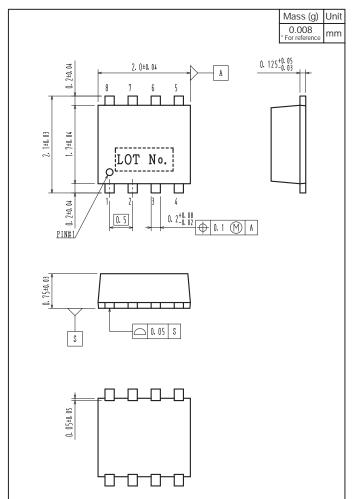




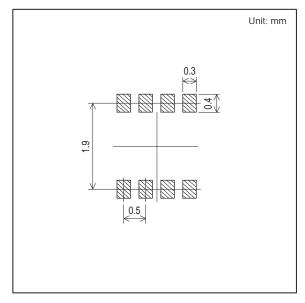
Those with pin 1 index on the feed hole side·····TL

## **Outline Drawing**

### EMH2407-TL-H



#### Land Pattern Example



Note on usage: Since the EMH2407 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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